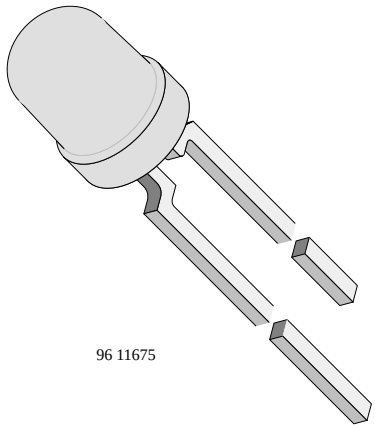
High Intensity LED in ø 3 mm Tinted Diffused Package

Color	Type	Technology	Angle of Half Intensity ±φ
Yellow	TLHE4400	AlInGaP on GaAs	30°

Description

This device has been designed to meet the increasing demand for AlInGaP technology general indicating and lighting purposes
It is housed in a 3 mm diffused plastic package. The wide viewing angle of these devices provides a high brightness.
All LEDs are categorized in luminous intensity groups. That allows users to assemble LEDs with uniform appearance.



Features

- AlInGaP technology
- Standard ø 3 mm (T-1) package
- Small mechanical tolerances
- Suitable for DC and high peak current
- Wide viewing angle
- Very high intensity
- Luminous intensity categorized

Applications

Status lights
OFF / ON indicator
Background illumination
Readout lights
Maintenance lights
Legend light

Absolute Maximum Ratings

T_{amb} = 25°C, unless otherwise specified

TLHE4400

Parameter	Test Conditions	Symbol	Value	Unit
Reverse voltage		V_R	5	V
DC forward current	$T_{amb} \leq 60°C$	I_F	30	mA
Surge forward current	$t_p \leq 10\ \mu s$	I_{FSM}	0.1	A
Power dissipation	$T_{amb} \leq 60°C$	P_V	80	mW
Junction temperature		T_j	100	°C
Operating temperature range		T_{amb}	–40 to +100	°C
Storage temperature range		T_{stg}	–55 to +100	°C
Soldering temperature	t ≤ 5 s, 2 mm from body	T_{sd}	260	°C
Thermal resistance junction/ambient		R_{thJA}	400	K/W

Optical and Electrical Characteristics

T_{amb} = 25°C, unless otherwise specified

Yellow (**TLHE4400**)

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Luminous intensity	I_F = 10 mA		I_V	25	80		mcd
Dominant wavelength	I_F = 10 mA		λ_d	581	588	594	nm
Peak wavelength	I_F = 10 mA		λ_p		590		nm
Angle of half intensity	I_F = 10 mA		φ		±30		deg
Forward voltage	I_F = 20 mA		V_F		1.9	2.6	V
Reverse voltage	I_R = 10 μA		V_R	5			V
Junction capacitance	V_R = 0, f = 1 MHz		C_j		15		pF

Typical Characteristics (T_{amb} = 25°C, unless otherwise specified)

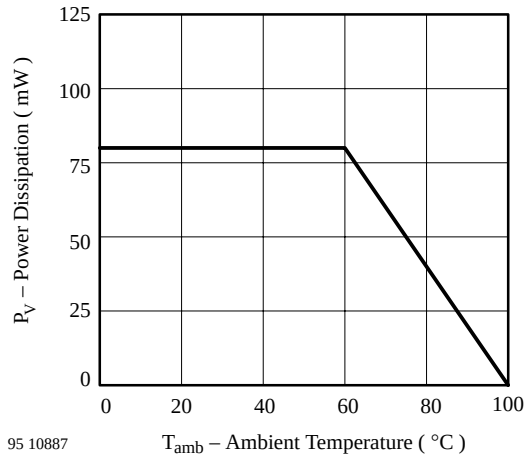


Figure 1 Power Dissipation vs. Ambient Temperature

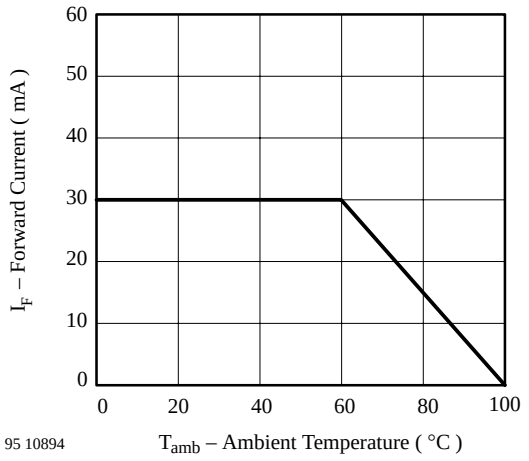


Figure 2 Forward Current vs. Ambient Temperature

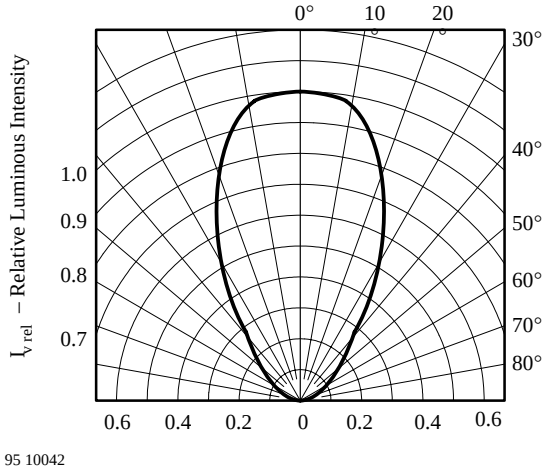


Figure 3 Rel. Luminous Intensity vs. Angular Displacement

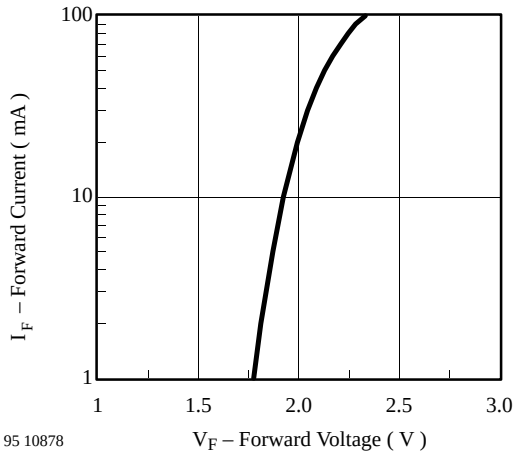


Figure 4 Forward Current vs. Forward Voltage

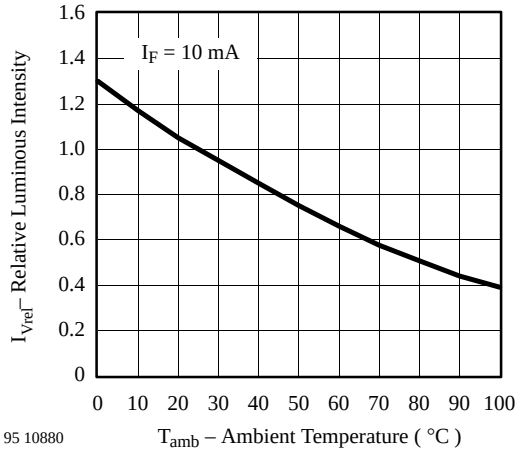


Figure 5 Rel. Luminous Intensity vs. Ambient Temperature

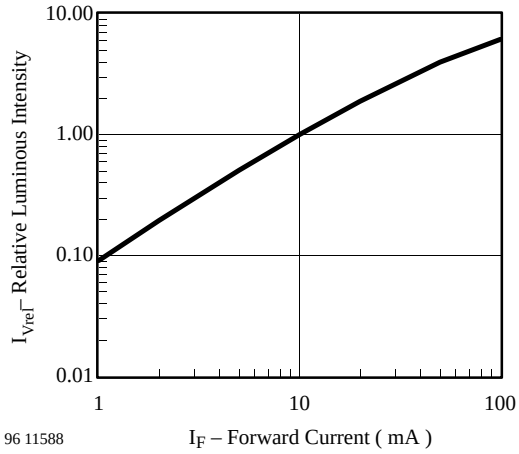


Figure 6 Relative Luminous Intensity vs. Forward Current

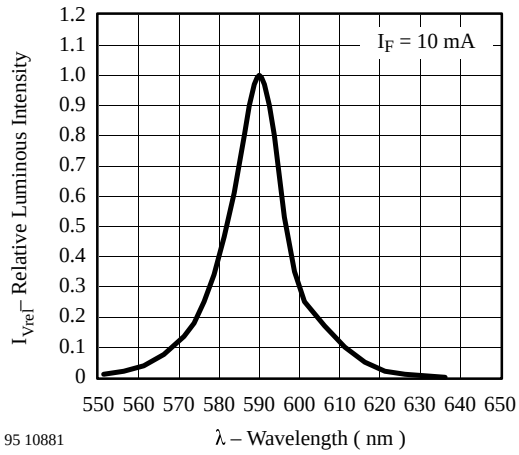
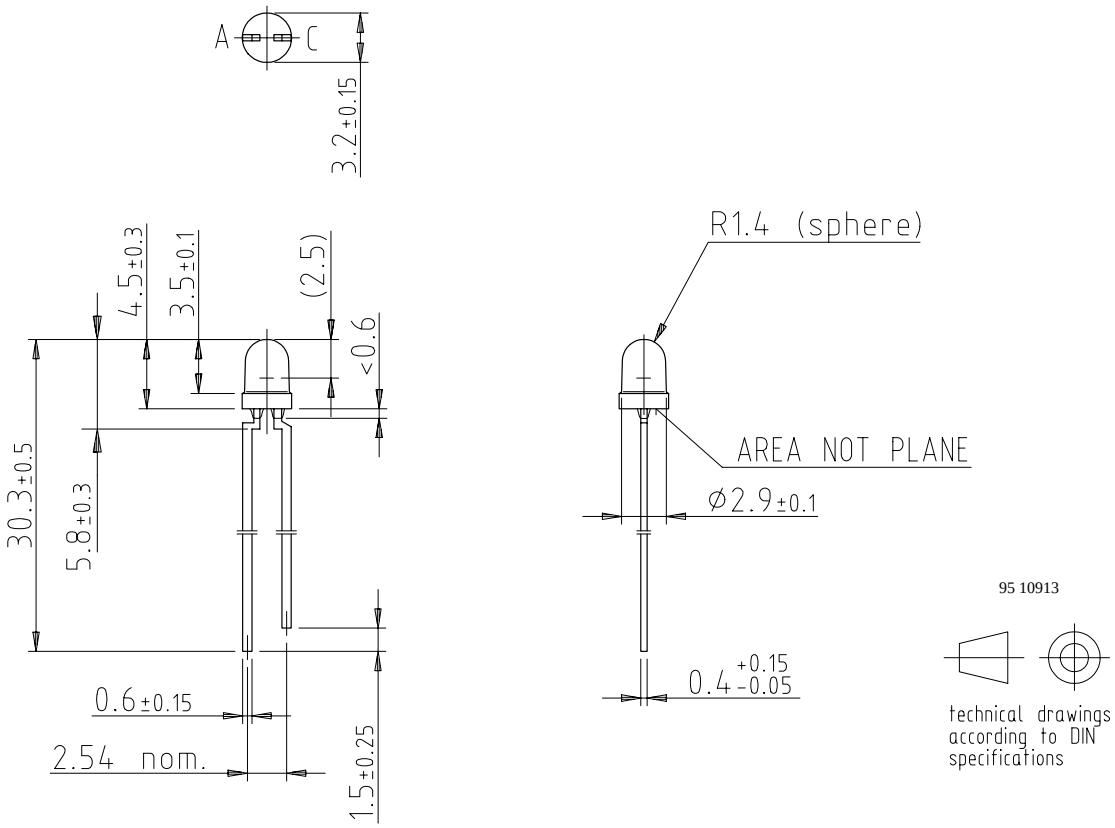


Figure 7 Relative Luminous Intensity vs. Wavelength

Dimensions in mm



Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.

2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively

2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA

3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany
Telephone: 49 (0)7131 67 2831, Fax number: 49 (0)7131 67 2423